

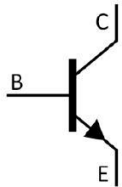
WR0<5+U, M M E QSQ æ M y s ll 1 Silicon NPN transistor in a TO-92(R) Plastic Package.

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High voltage, complementary to BC556.

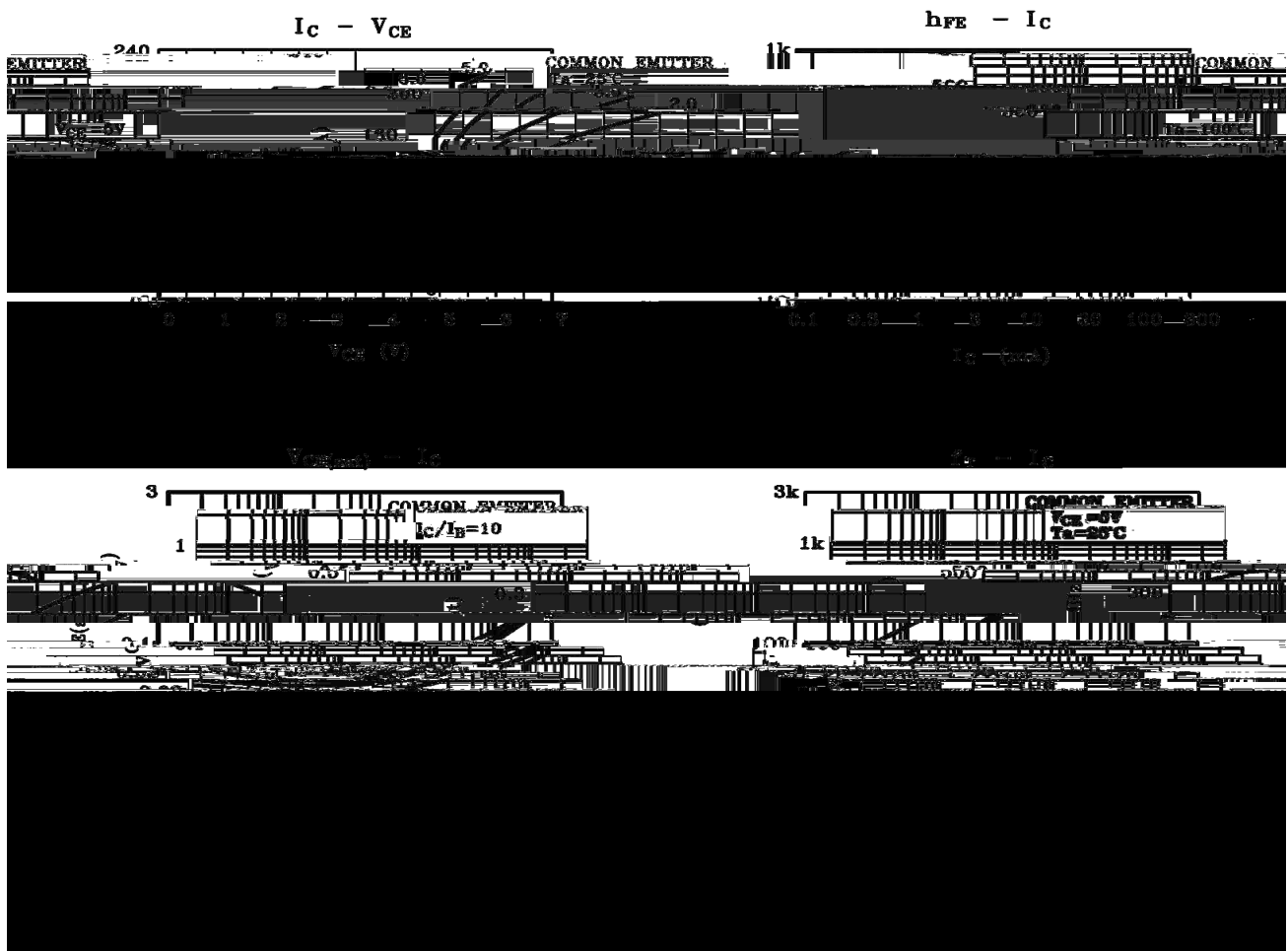
[illegible]

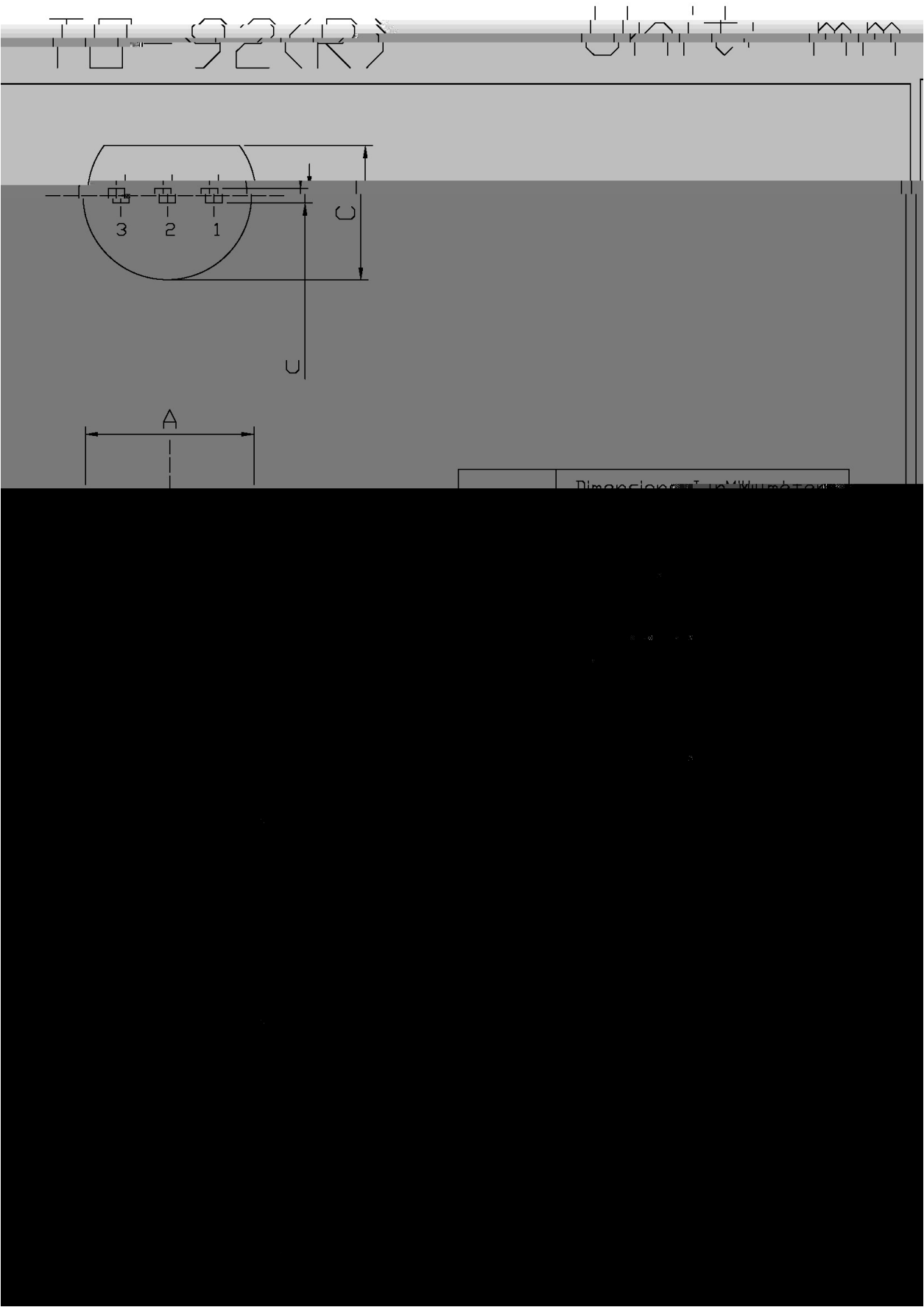
General purpose and switching application.

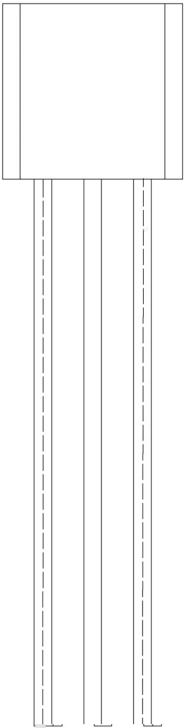
PIN1 χ EmitterPIN 2 χ BasePIN 3 χ Collector

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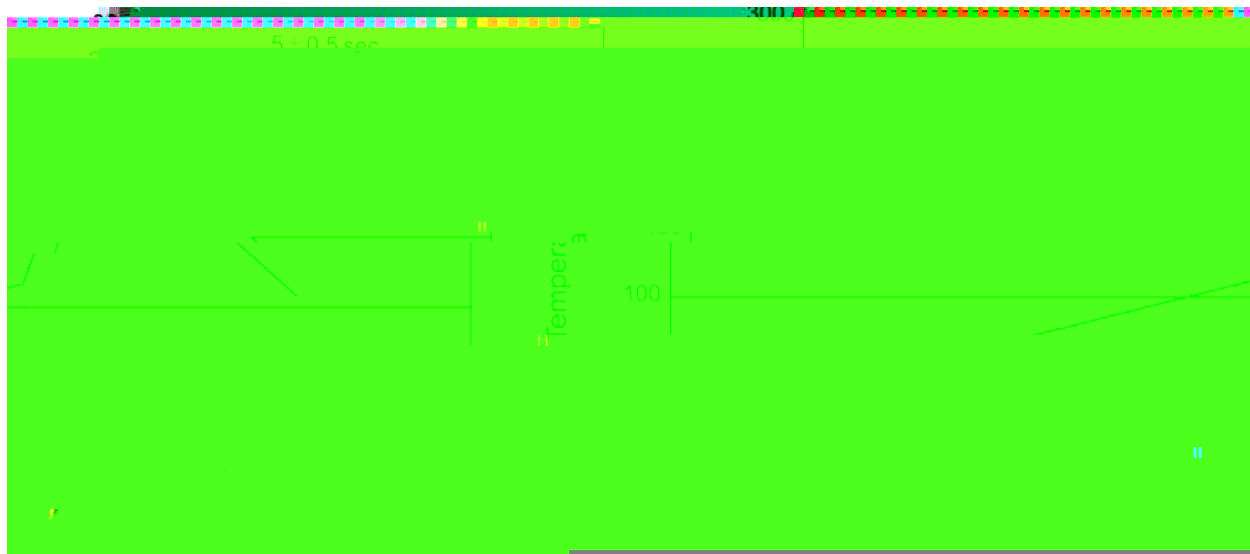
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尺寸
EU 封装 3 脚
EF879 封装 4 脚
= 4 脚封装



б " X

1. $150 \pm 5^\circ \text{C}$ $60 \sim 90 \text{ sec}$;
2. $255 \pm 5^\circ \text{C}$ $5 \pm 0.5 \text{ sec}$;
3. $2 \sim 10^\circ \text{C/sec}$.

Note:

1. Preheating: $25 \sim 150^\circ \text{C}$, Time: $60 \sim 90 \text{ sec}$.
2. Peak Temp.: $255 \pm 5^\circ \text{C}$, Duration: $5 \pm 0.5 \text{ sec}$.
3. Cooling Speed: $2 \sim 10^\circ \text{C/sec}$.

$270 \pm 5^\circ \text{C}$

$10 \pm 1 \text{ sec}$.

Temp.: 270 ± 5

Time: $10 \pm 1 \text{ sec}$

“Q” γ E / BULK

Package Type	Units					Dimension (unit mm3)		
	Units/Bag /	Bags/Inner Box /	Units/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Bag	Inner Box	Outer Box
TO-92	1,000	10	10,000	5	50,000	135×190	237×172×102	560×245×195
	1,000	10	10,000	10	100,000	135×190	237×172×102	560×245×375

λ γ E / AMMO

Package Type	Units					Dimension (unit mm3)	
	Units/tape /	Tape/Inner Box /	Rows/Inner Box /	Inner Boxes/Outer Box /	Units/Outer Box /	Inner Box	Outer Box
TO-92	3,000	1	120	10	30,000	328×230×42	480×346×235 547×407×268